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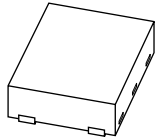
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Kind regards,

Team Nexperia



# PMEG3020EPA

2 A low  $V_F$  MEGA Schottky barrier rectifier

Rev. 01 — 15 December 2009

Product data sheet

## 1. Product profile

### 1.1 General description

Planar Maximum Efficiency General Application (MEGA) Schottky barrier rectifier with an integrated guard ring for stress protection. PMEG3020EPA is encapsulated in an ultra thin SOT1061 leadless small Surface-Mounted Device (SMD) plastic package with medium power capability.

### 1.2 Features

- Average forward current:  $I_{F(AV)} \leq 2$  A
- Reverse voltage:  $V_R \leq 30$  V
- Low forward voltage
- Exposed heat sink (cathode pad) for excellent thermal and electrical conductivity
- Leadless small SMD plastic package with medium power capability
- AEC-Q101 qualified

### 1.3 Applications

- Low voltage rectification
- High efficiency DC-to-DC conversion
- Switch Mode Power Supply (SMPS)
- Reverse polarity protection
- Low power consumption applications
- Battery chargers for mobile equipment

### 1.4 Quick reference data

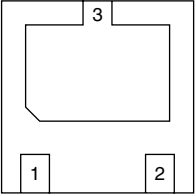
**Table 1. Quick reference data**  
 $T_j = 25$  °C unless otherwise specified.

| Symbol      | Parameter               | Conditions                                       | Min | Typ | Max  | Unit    |
|-------------|-------------------------|--------------------------------------------------|-----|-----|------|---------|
| $I_{F(AV)}$ | average forward current | square wave;<br>$\delta = 0.5$ ;<br>$f = 20$ kHz |     |     |      |         |
|             |                         | $T_{amb} \leq 65$ °C                             | [1] | -   | 2    | A       |
|             |                         | $T_{sp} \leq 140$ °C                             | -   | -   | 2    | A       |
| $V_R$       | reverse voltage         |                                                  | -   | -   | 30   | V       |
| $V_F$       | forward voltage         | $I_F = 2$ A                                      | -   | 410 | 470  | mV      |
| $I_R$       | reverse current         | $V_R = 30$ V                                     | -   | 435 | 2500 | $\mu$ A |

[1] Device mounted on a ceramic Printed-Circuit Board (PCB),  $Al_2O_3$ , standard footprint.

## 2. Pinning information

Table 2. Pinning

| Pin | Description | Simplified outline                                                                                              | Graphic symbol                                                                                       |
|-----|-------------|-----------------------------------------------------------------------------------------------------------------|------------------------------------------------------------------------------------------------------|
| 1   | anode       |  <p>Transparent top view</p> |  <p>006aab624</p> |
| 2   | anode       |                                                                                                                 |                                                                                                      |
| 3   | cathode     |                                                                                                                 |                                                                                                      |

## 3. Ordering information

Table 3. Ordering information

| Type number | Package |                                                                                                                        |         |
|-------------|---------|------------------------------------------------------------------------------------------------------------------------|---------|
|             | Name    | Description                                                                                                            | Version |
| PMEG3020EPA | HUSON3  | plastic thermal enhanced ultra thin small outline package; no leads; three terminals; body $2 \times 2 \times 0.65$ mm | SOT1061 |

## 4. Marking

Table 4. Marking codes

| Type number | Marking code |
|-------------|--------------|
| PMEG3020EPA | A2           |

## 5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol      | Parameter                           | Conditions                                              | Min      | Max  | Unit |
|-------------|-------------------------------------|---------------------------------------------------------|----------|------|------|
| $V_R$       | reverse voltage                     | $T_J = 25\text{ }^\circ\text{C}$                        | -        | 30   | V    |
| $I_{F(AV)}$ | average forward current             | square wave;<br>$\delta = 0.5$ ;<br>$f = 20\text{ kHz}$ |          |      |      |
|             |                                     | $T_{amb} \leq 65\text{ }^\circ\text{C}$                 | [1] -    | 2    | A    |
|             |                                     | $T_{sp} \leq 140\text{ }^\circ\text{C}$                 | -        | 2    | A    |
| $I_{FRM}$   | repetitive peak forward current     | $t_p \leq 1\text{ ms}$ ;<br>$\delta \leq 0.25$          | [2] -    | 7    | A    |
| $I_{FSM}$   | non-repetitive peak forward current | square wave;<br>$t_p = 8\text{ ms}$                     | [2][3] - | 17   | A    |
| $P_{tot}$   | total power dissipation             | $T_{amb} \leq 25\text{ }^\circ\text{C}$                 | [4][5] - | 500  | mW   |
|             |                                     |                                                         | [4][6] - | 960  | mW   |
|             |                                     |                                                         | [4][1] - | 1800 | mW   |

**Table 5. Limiting values ...continued***In accordance with the Absolute Maximum Rating System (IEC 60134).*

| Symbol    | Parameter            | Conditions | Min | Max  | Unit |
|-----------|----------------------|------------|-----|------|------|
| $T_j$     | junction temperature |            | -   | 150  | °C   |
| $T_{amb}$ | ambient temperature  |            | -55 | +150 | °C   |
| $T_{stg}$ | storage temperature  |            | -65 | +150 | °C   |

[1] Device mounted on a ceramic PCB,  $Al_2O_3$ , standard footprint.

[2] Both anode pins connected.

[3]  $T_j = 25$  °C prior to surge.

[4] Reflow soldering is the only recommended soldering method.

[5] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[6] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm<sup>2</sup>.

## 6. Thermal characteristics

**Table 6. Thermal characteristics**

| Symbol         | Parameter                                        | Conditions  | Min    | Typ | Max | Unit    |
|----------------|--------------------------------------------------|-------------|--------|-----|-----|---------|
| $R_{th(j-a)}$  | thermal resistance from junction to ambient      | in free air | [1][2] |     |     |         |
|                |                                                  |             | [3]    | -   | -   | 250 K/W |
|                |                                                  |             | [4]    | -   | -   | 130 K/W |
|                |                                                  |             | [5]    | -   | -   | 70 K/W  |
| $R_{th(j-sp)}$ | thermal resistance from junction to solder point |             | [6]    | -   | -   | 12 K/W  |

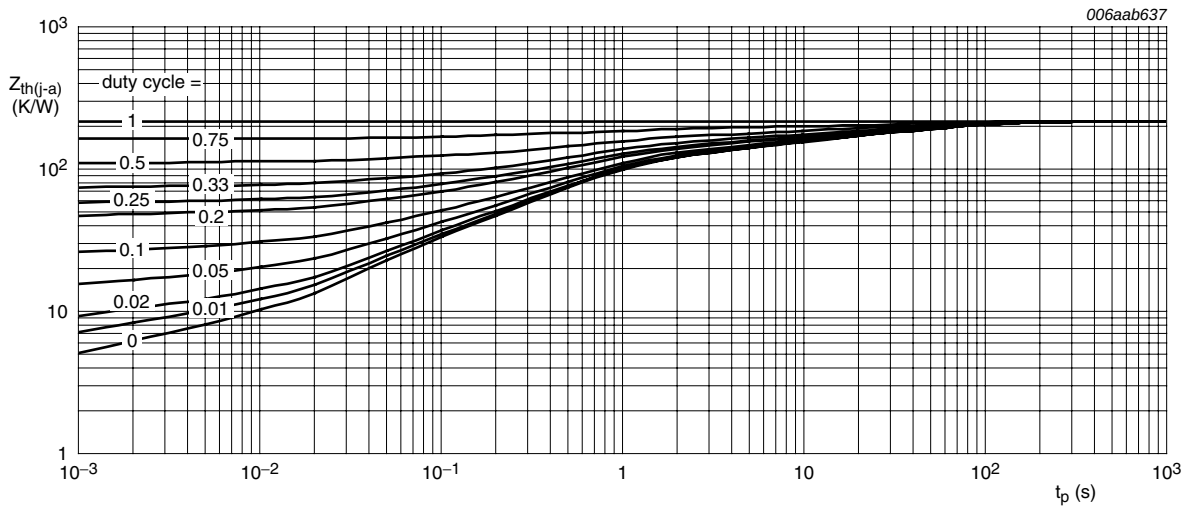
[1] For Schottky barrier diodes thermal runaway has to be considered, as in some applications the reverse power losses  $P_R$  are a significant part of the total power losses.

[2] Reflow soldering is the only recommended soldering method.

[3] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

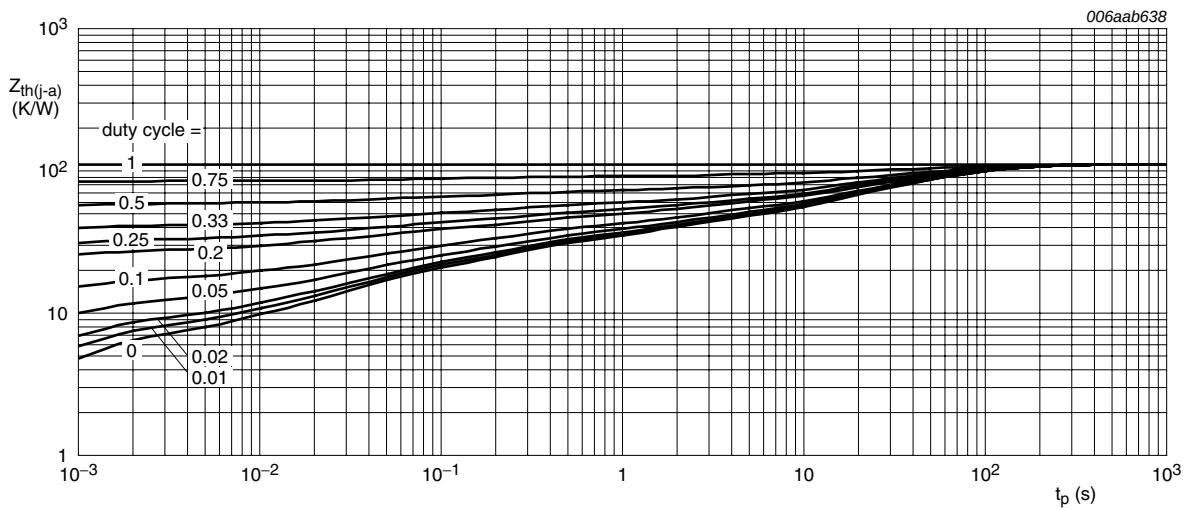
[4] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm<sup>2</sup>.[5] Device mounted on a ceramic PCB,  $Al_2O_3$ , standard footprint.

[6] Soldering point of cathode tab.



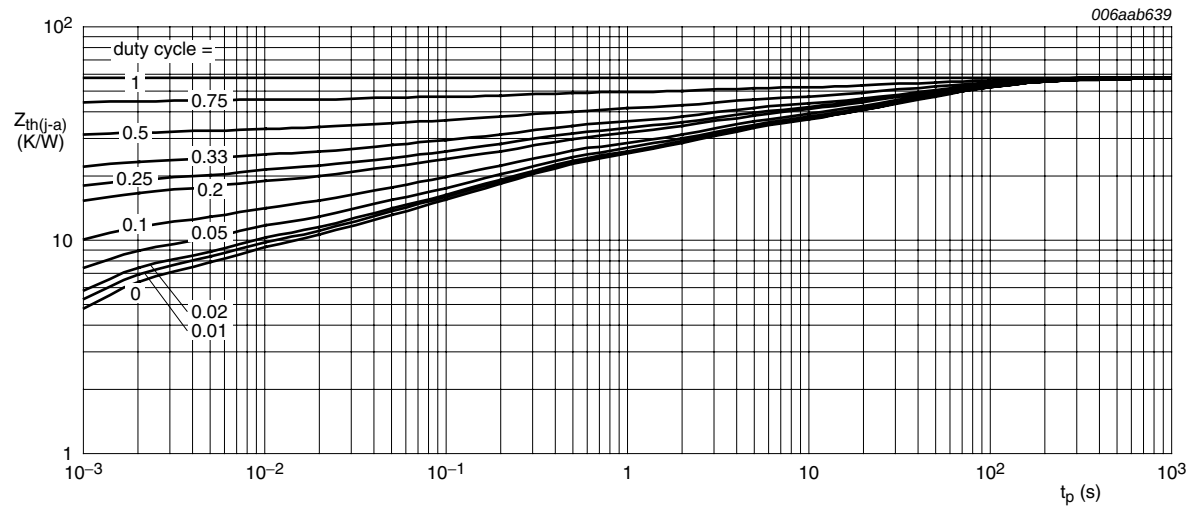
FR4 PCB, standard footprint

Fig 1. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



FR4 PCB, mounting pad for cathode 1 cm<sup>2</sup>

Fig 2. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



Ceramic PCB,  $Al_2O_3$ , standard footprint

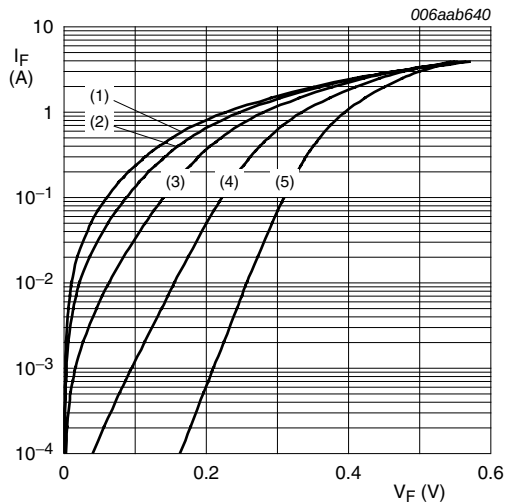
Fig 3. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

7. Characteristics

Table 7. Characteristics  
 $T_j = 25\text{ }^{\circ}C$  unless otherwise specified.

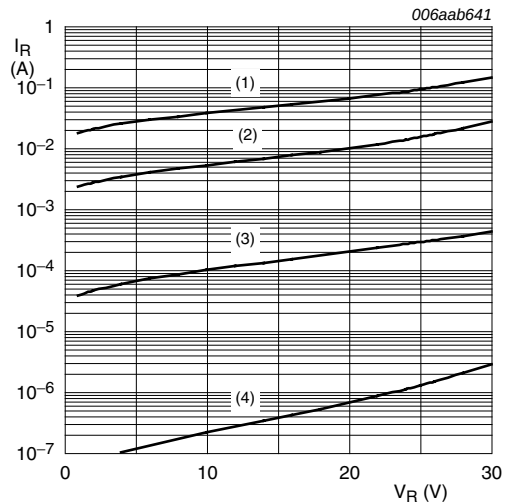
| Symbol   | Parameter             | Conditions           | Min | Typ | Max  | Unit    |
|----------|-----------------------|----------------------|-----|-----|------|---------|
| $V_F$    | forward voltage       | $I_F = 0.5\text{ A}$ | -   | 290 | -    | mV      |
|          |                       | $I_F = 1\text{ A}$   | -   | 335 | -    | mV      |
|          |                       | $I_F = 2\text{ A}$   | -   | 410 | 470  | mV      |
| $I_R$    | reverse current       | $V_R = 10\text{ V}$  | -   | 100 | -    | $\mu A$ |
|          |                       | $V_R = 30\text{ V}$  | -   | 435 | 2500 | $\mu A$ |
| $C_d$    | diode capacitance     | $f = 1\text{ MHz}$   |     |     |      |         |
|          |                       | $V_R = 1\text{ V}$   | -   | 150 | -    | pF      |
|          |                       | $V_R = 10\text{ V}$  | -   | 55  | -    | pF      |
| $t_{rr}$ | reverse recovery time | [1]                  | -   | 47  | -    | ns      |

[1] When switched from  $I_F = 10\text{ mA}$  to  $I_R = 10\text{ mA}$ ;  $R_L = 100\text{ }\Omega$ ; measured at  $I_R = 1\text{ mA}$ .



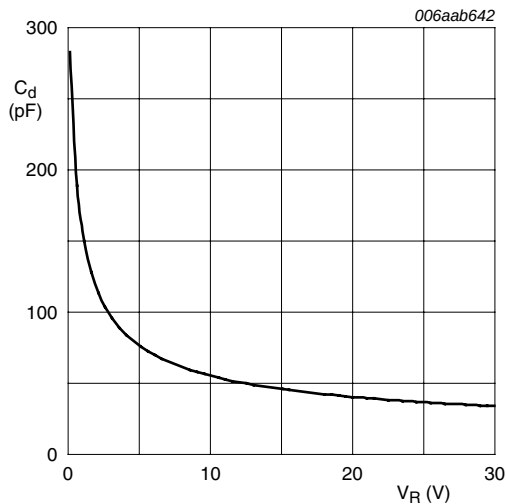
- (1)  $T_j = 150^\circ\text{C}$
- (2)  $T_j = 125^\circ\text{C}$
- (3)  $T_j = 85^\circ\text{C}$
- (4)  $T_j = 25^\circ\text{C}$
- (5)  $T_j = -40^\circ\text{C}$

Fig 4. Forward current as a function of forward voltage; typical values



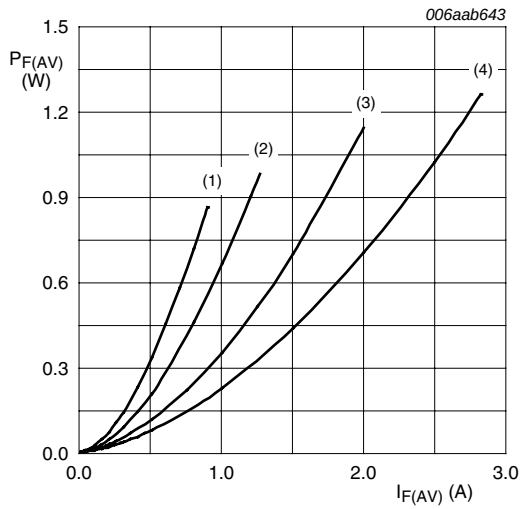
- (1)  $T_j = 125^\circ\text{C}$
- (2)  $T_j = 85^\circ\text{C}$
- (3)  $T_j = 25^\circ\text{C}$
- (4)  $T_j = -40^\circ\text{C}$

Fig 5. Reverse current as a function of reverse voltage; typical values



$f = 1\text{ MHz}$ ;  $T_{\text{amb}} = 25^\circ\text{C}$

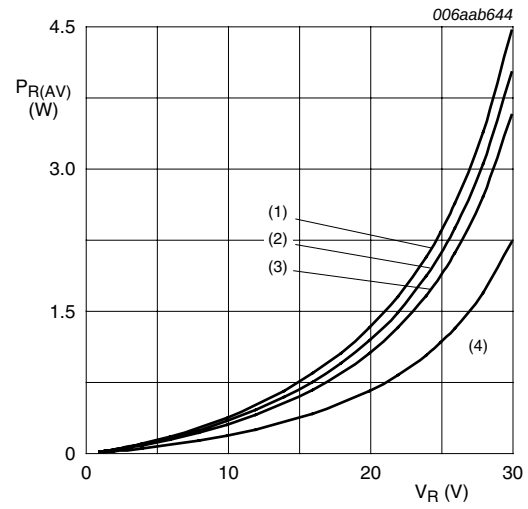
Fig 6. Diode capacitance as a function of reverse voltage; typical values



$T_j = 150\text{ °C}$

- (1)  $\delta = 0.1$
- (2)  $\delta = 0.2$
- (3)  $\delta = 0.5$
- (4)  $\delta = 1$

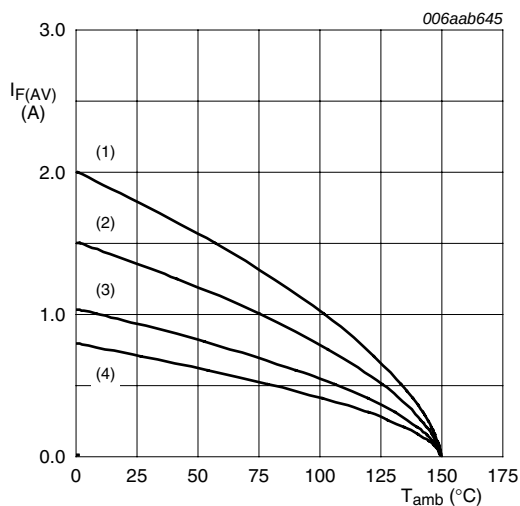
**Fig 7.** Average forward power dissipation as a function of average forward current; typical values



$T_j = 125\text{ °C}$

- (1)  $\delta = 1$
- (2)  $\delta = 0.9$
- (3)  $\delta = 0.8$
- (4)  $\delta = 0.5$

**Fig 8.** Average reverse power dissipation as a function of reverse voltage; typical values

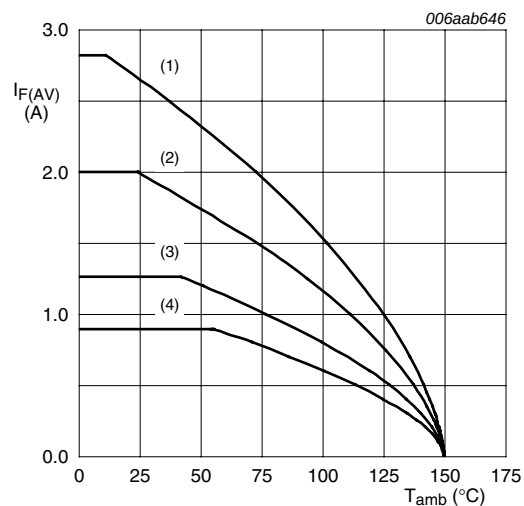


FR4 PCB, standard footprint

$T_j = 150\text{ °C}$

- (1)  $\delta = 1$ ; DC
- (2)  $\delta = 0.5$ ;  $f = 20\text{ kHz}$
- (3)  $\delta = 0.2$ ;  $f = 20\text{ kHz}$
- (4)  $\delta = 0.1$ ;  $f = 20\text{ kHz}$

**Fig 9.** Average forward current as a function of ambient temperature; typical values



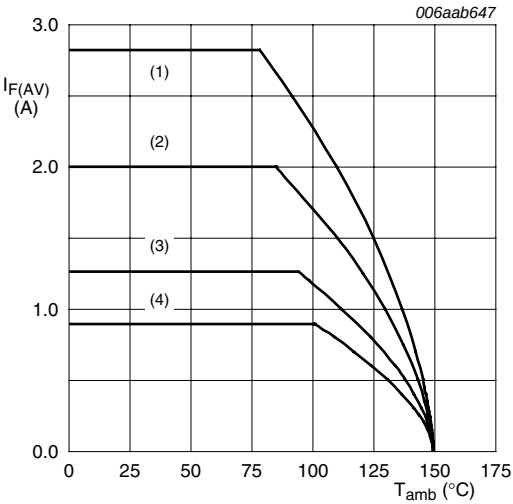
FR4 PCB, mounting pad for cathode  $1\text{ cm}^2$

$T_j = 150\text{ °C}$

- (1)  $\delta = 1$ ; DC
- (2)  $\delta = 0.5$ ;  $f = 20\text{ kHz}$
- (3)  $\delta = 0.2$ ;  $f = 20\text{ kHz}$
- (4)  $\delta = 0.1$ ;  $f = 20\text{ kHz}$

**Fig 10.** Average forward current as a function of ambient temperature; typical values



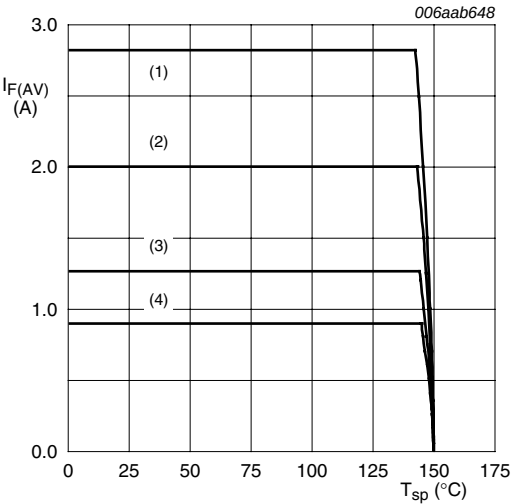


Ceramic PCB,  $Al_2O_3$ , standard footprint

$T_j = 150$  °C

- (1)  $\delta = 1$ ; DC
- (2)  $\delta = 0.5$ ;  $f = 20$  kHz
- (3)  $\delta = 0.2$ ;  $f = 20$  kHz
- (4)  $\delta = 0.1$ ;  $f = 20$  kHz

**Fig 11.** Average forward current as a function of ambient temperature; typical values

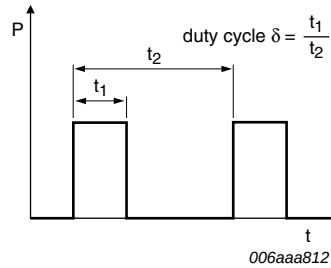


$T_j = 150$  °C

- (1)  $\delta = 1$ ; DC
- (2)  $\delta = 0.5$ ;  $f = 20$  kHz
- (3)  $\delta = 0.2$ ;  $f = 20$  kHz
- (4)  $\delta = 0.1$ ;  $f = 20$  kHz

**Fig 12.** Average forward current as a function of solder point temperature; typical values

## 8. Test information



**Fig 13. Duty cycle definition**

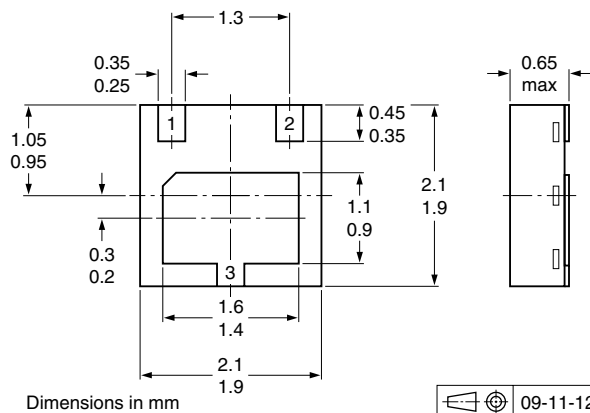
The current ratings for the typical waveforms as shown in [Figure 9](#), [10](#), [11](#) and [12](#) are calculated according to the equations:  $I_{F(AV)} = I_M \times \delta$  with  $I_M$  defined as peak current,

$I_{RMS} = I_{F(AV)}$  at DC, and  $I_{RMS} = I_M \times \sqrt{\delta}$  with  $I_{RMS}$  defined as RMS current.

### 8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101 - Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

## 9. Package outline



**Fig 14. Package outline SOT1061**

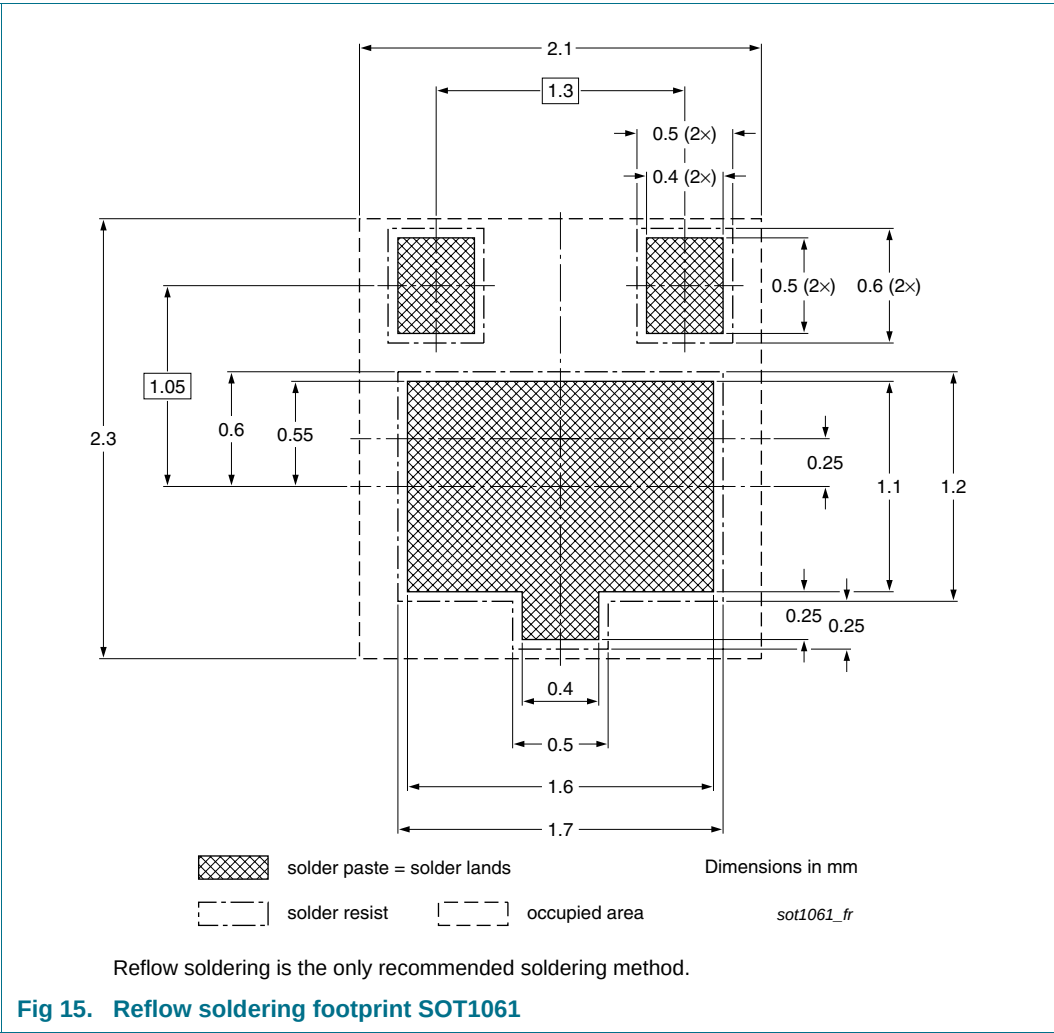
10. Packing information

Table 8. Packing methods  
The indicated -xxx are the last three digits of the 12NC ordering code.<sup>[1]</sup>

| Type number | Package | Description                    | Packing quantity |
|-------------|---------|--------------------------------|------------------|
|             |         |                                | 3000             |
| PMEG3020EPA | SOT1061 | 4 mm pitch, 8 mm tape and reel | -115             |

[1] For further information and the availability of packing methods, see [Section 14](#).

11. Soldering



## 12. Revision history

Table 9. Revision history

| Document ID   | Release date | Data sheet status  | Change notice | Supersedes |
|---------------|--------------|--------------------|---------------|------------|
| PMEG3020EPA_1 | 20091215     | Product data sheet | -             | -          |

## 13. Legal information

### 13.1 Data sheet status

| Document status <sup>[1][2]</sup> | Product status <sup>[3]</sup> | Definition                                                                            |
|-----------------------------------|-------------------------------|---------------------------------------------------------------------------------------|
| Objective [short] data sheet      | Development                   | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet    | Qualification                 | This document contains data from the preliminary specification.                       |
| Product [short] data sheet        | Production                    | This document contains the product specification.                                     |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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